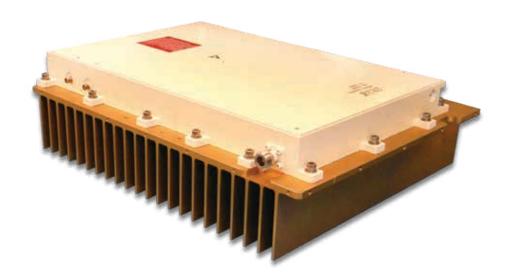
Communications & Power Industries Beverly Microwave Division High Power Solid State Amplifier



CPI-Built RF Power Modules

S-band Solid State Power Amplifiers produce high power and are compact with proven GaN transistor technology.

CPI's Solid State Power Amplifiers are rock-solid, highly-efficient and easy to maintain. The VSS3647 Solid State Power Amplifiers are designed for use in radar applications. Gallium Nitride transistors are combined into 1.5 kW bricks which are air cooled. The bricks can be power-combined using radial combiners and waveguide combiners for any power desired.

Optimized for Pulsed Radars

This amplifier utilizes GaN transistors to provide high gain, high efficiency and excellent pulse fidelity. The result is excellent AM/PM, phase-noise and spectral regrowth performance.

FEATURES:

- Frequency range: 3.1 3.5 GHz
- 1.5 kW pulsed modules
- High efficiency GaN transistors
- 10% RF duty operation
- BIT and controls via EIA-422 remote connection

BENEFITS:

- Easily power combined for any power level
- High efficiency
- Excellent pulse fidelity
- Excellent AM/PM, phase noise, and spectral regrowth performance



S-Band 1.5 kW Solid State Power Amplifier: VSS3647

Electrical Specifications

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Frequency	3.1 GHz - 3.5 GHz
Peak power output	1.5 kW saturated,
	minimum
Pulse width	1 to 100 µsec (typical)
Pulse droop	0.5 dB maximum
Duty Cycle	10% maximum
Output power flatness	1 dB across frequency
	range
Small signal gain	40 dB nominal
Input VSWR	1.5:1 maximum
Output VSWR	1.5:1 maximum
Harmonic output	-65 dBc maximum
Interpulse thermal noise	-165 dBc / MHz
	maximum
Noise power density	-100 dBc into a 1 MHz
	bandwidth
MTBF	>140,000 hours
NTIA compliance	Compliant with customer pulse shaping as required

Specifications

Prime Power	50 VDC @ 9 Amps
Ambient Temperature -32°C to +50°C operating	
Relative Humidity	100% non-condensing
Altitude	
Operating	30,000 feet (9.14 kM)
Non-operating	70,000 feet (21.34 kM)
Cooling	Forced Air
RF input connection	SMA female
RF output connection	Type N female
RF output monitor	Control connector
Dimensions (width)	10.5 in
Dimensions (height)	2.5 in
Dimensions (depth)	14.5 in
Weight	14 lbs max.
Internal cutout inclutor Duranial alfan (CN/D must ation	

Internal output isolator Provided for VSWR protection

